

DESCRIPTION

RST9361MA is a low-capacitance Transient Voltage Suppressor (TVS) designed to provide electrostatic discharge (ESD) protection for high-speed data interfaces. With typical capacitance of 0.25pF, RST9361MA is designed to protect parasitic-sensitive systems against over-voltage and over-current transient events. It complies with IEC 61000-4-2 (ESD), Level 4 (±15kV air, ±8kV contact discharge), IEC 61000-4-4 (electrical fast transient - EFT) (40A, 5/50 ns), very fast charged device model (CDM) ESD and cable discharge event (CDE), etc.

RST9361MA uses ultra-small DFN1006 package. Each RST9361MA device can protect one high-speed data line. It offers system designers flexibility to protect single data line where space is a premium concern. The combined features of low capacitance, ultra-small size and high ESD robustness make RST9361MA ideal for high-speed data port and high-frequency line applications, such as cellular phones and HD visual devices.

FEATURES

♦ Transient protection for high-speed data lines IEC 61000-4-2 (ESD) ±15kV (Air) ±8kV (Contact)

IEC 61000-4-4 (EFT) 40A (5/50 ns) Cable Discharge Event (CDE)

- ♦ Package optimized for high-speed lines
- ♦ Ultra-small package (1.0mm×0.6mm×0.5mm)
- ♦ Protects one data, control line
- ♦ Low capacitance: 0.25pF (Typical)
- ♦ Low leakage current
- ♦ Low clamping voltage

MACHANICAL DATA

- ♦DFN1006 package
- ♦ Flammability Rating: UL 94V-0
- ♦ Packaging: Tape and Reel
- ♦ High temperature soldering guaranted:260°C/10s
- ♦Reel size: 7 inch

ORDERING INFORMATION

Device: RST9361MAPackage: DFN1006

♦ Marking: 3B

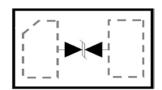
→ Material: Halogen free→ Packing: Tape & Reel

♦ Quantity per reel: 10,000pcs

APPLICATIONS

- ♦ Serial ATA
- ♦ Desktops, Servers and Notebooks
- ♦ Cellular Phones
- **♦ MDDI Ports**
- ♦USB Data Line Protection
- ♦ Display Ports
- ♦ Digital Visual Interfaces (DVI)

PIN CONFIGURATION



CIRCUIT DIAGRAM





ABSOLUTE MAXIMUM RATING						
Symbol	Parameter	Value	Units			
V_{ESD}	ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	±20 ±20	kV			
P _{PP}	Peak Pulse Power (8/20µs)	84	W			
T _{OPT}	Operating Temperature	-55~125	°C			
T _{STG}	Storage Temperature	-55~150	°C			

ELECTRICAL CHARACTERISTICS (Tamb=25°C)									
Symbol	Parameter	Test Condition	Min	Тур	Max	Units			
V_{RWM}	Reverse Working Voltage				3.3	V			
V_{BR}	Reverse Breakdown Voltage	I _T = 1mA	4.2			V			
I _R	Reverse Leakage Current	$V_{RWM} = 3.3V$			100	nA			
Vc	Clamping Voltage	$I_{PP} = 1A, t_p = 8/20 \mu s$			12	V			
		$I_{PP} = 4A, t_p = 8/20 \mu s$			21	V			
CJ	Junction Capacitance	$V_R = 0V$, $f = 1MHz$	_	0.25		pF			



